

## Features

- Serial Peripheral Interface (SPI) Compatible
- Supports SPI Modes 0 (0,0) and 3 (1,1)
- Low-voltage and Standard-voltage Operation
  - 2.7 ( $V_{CC} = 2.7V$  to 5.5V)
- 3.0 MHz Clock Rate (5V)
- 8-byte Page Mode
- Block Write Protection
  - Protect 1/4, 1/2, or Entire Array
- Write Protect ( $\overline{WP}$ ) Pin and Write Disable Instructions for Both Hardware and Software Data Protection
- Self-timed Write Cycle (10 ms max)
- High Reliability
  - Endurance: One Million Write Cycles
  - Data Retention: 100 Years
- Automotive Grade, Extended Temperature and Lead-Free Devices Available
- 8-lead PDIP, 8-lead JEDEC SOIC, 8-lead MAP and 8-lead TAP Packages

## Description

The AT25010/020/040 provides 1024/2048/4096 bits of serial electrically erasable programmable read only memory (EEPROM) organized as 128/256/512 words of 8 bits each. The device is optimized for use in many industrial and commercial applications where low-power and low voltage operation are essential. The AT25010/020/040 is available in space saving 8-lead PDIP, 8-lead JEDEC SOIC, 8-lead MAP and 8-lead TAP packages.

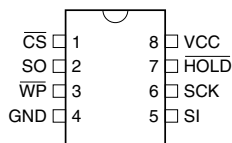
The AT25010/020/040 is enabled through the Chip Select pin ( $\overline{CS}$ ) and accessed via a 3-wire interface consisting of Serial Data Input (SI), Serial Data Output (SO), and Serial Clock (SCK). All programming cycles are completely self-timed, and no separate ERASE cycle is required before WRITE.

BLOCK WRITE protection is enabled by programming the status register with one of four blocks of write protection. Separate program enable and program disable instructions are provided for additional data protection. Hardware data protection is provided via the  $\overline{WP}$  pin to protect against inadvertent write attempts. The  $\overline{HOLD}$  pin may be used to suspend any serial communication without resetting the serial sequence.

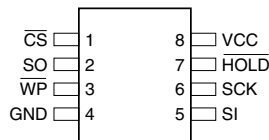
## Pin Configurations

| Pin Name          | Function              |
|-------------------|-----------------------|
| $\overline{CS}$   | Chip Select           |
| SCK               | Serial Data Clock     |
| SI                | Serial Data Input     |
| SO                | Serial Data Output    |
| GND               | Ground                |
| VCC               | Power Supply          |
| $\overline{WP}$   | Write Protect         |
| $\overline{HOLD}$ | Suspends Serial Input |

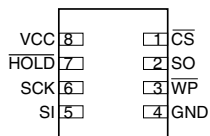
8-lead PDIP



8-lead SOIC



8-lead MAP/TAP



Bottom View



## SPI Serial EEPROMs

1K (128 x 8)

2K (256 x 8)

4K (512 x 8)

AT25010

AT25020

AT25040

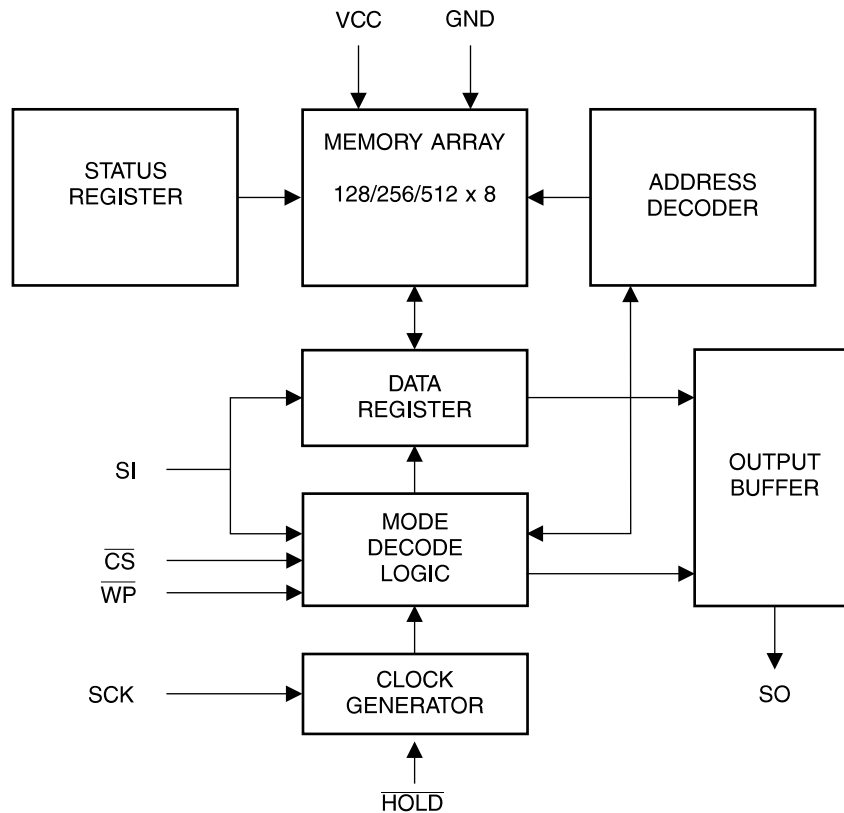


## Absolute Maximum Ratings\*

|                                                    |                  |
|----------------------------------------------------|------------------|
| Operating Temperature .....                        | -55°C to + 125°C |
| Storage Temperature .....                          | -65°C to + 150°C |
| Voltage on Any Pin<br>with Respect to Ground ..... | -1.0V to + 7.0V  |
| Maximum Operating Voltage .....                    | 6.25V            |
| DC Output Current.....                             | 5.0 mA           |

**\*NOTICE:** Stresses beyond those listed under “Absolute Maximum Ratings” may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

## Block Diagram



## Pin Capacitance<sup>(1)</sup>

Applicable over recommended operating range from  $T_A = 25^\circ\text{C}$ ,  $f = 1.0\text{ MHz}$ ,  $V_{CC} = +5.0\text{V}$  (unless otherwise noted).

| Symbol    | Test Conditions                                                                      | Max | Units | Conditions            |
|-----------|--------------------------------------------------------------------------------------|-----|-------|-----------------------|
| $C_{OUT}$ | Output Capacitance (SO)                                                              | 8   | pF    | $V_{OUT} = 0\text{V}$ |
| $C_{IN}$  | Input Capacitance ( $\overline{CS}$ , SCK, SI, $\overline{WP}$ , $\overline{HOLD}$ ) | 6   | pF    | $V_{IN} = 0\text{V}$  |

Note: 1. This parameter is characterized and is not 100% tested.

## DC Characteristics

Applicable over recommended operating range from:  $T_{AI} = -40^\circ\text{C}$  to  $+85^\circ\text{C}$ ,  $V_{CC} = +2.7\text{V}$  to  $+5.5\text{V}$ ,  $T_{AE} = -40^\circ\text{C}$  to  $+125^\circ\text{C}$ ,  $V_{CC} = +2.7\text{V}$  to  $+5.5\text{V}$  (unless otherwise noted).

| Symbol         | Parameter           | Test Condition                                                                      | Min                                | Max                 | Units         |
|----------------|---------------------|-------------------------------------------------------------------------------------|------------------------------------|---------------------|---------------|
| $V_{CC1}$      | Supply Voltage      |                                                                                     | 2.7                                | 5.5                 | V             |
| $V_{CC2}$      | Supply Voltage      |                                                                                     | 4.5                                | 5.5                 | V             |
| $I_{CC1}$      | Supply Current      | $V_{CC} = 5.0\text{V}$ at 1 MHz, SO = Open, Read                                    |                                    | 3.0                 | mA            |
| $I_{CC2}$      | Supply Current      | $V_{CC} = 5.0\text{V}$ at 2 MHz, SO = Open, Read, Write                             |                                    | 6.0                 | mA            |
| $I_{SB1}$      | Standby Current     | $V_{CC} = 2.7\text{V}$ $\overline{CS} = V_{CC}$                                     |                                    | 5                   | $\mu\text{A}$ |
| $I_{SB2}$      | Standby Current     | $V_{CC} = 5.0\text{V}$ $\overline{CS} = V_{CC}$                                     |                                    | 10                  | $\mu\text{A}$ |
| $I_{IL}$       | Input Leakage       | $V_{IN} = 0\text{V}$ to $V_{CC}$                                                    | -0.6                               | 3.0                 | $\mu\text{A}$ |
| $I_{OL}$       | Output Leakage      | $V_{IN} = 0\text{V}$ to $V_{CC}$ , $T_{AC} = 0^\circ\text{C}$ to $70^\circ\text{C}$ | -0.6                               | 3.0                 | $\mu\text{A}$ |
| $V_{IL}^{(2)}$ | Input Low Voltage   |                                                                                     | -0.6                               | $V_{CC} \times 0.3$ | V             |
| $V_{IH}^{(2)}$ | Input High Voltage  |                                                                                     | $V_{CC} \times 0.7$                | $V_{CC} + 0.5$      | V             |
| $V_{OL1}$      | Output Low Voltage  | $4.5\text{V} \leq V_{CC} \leq 5.5\text{V}$                                          | $I_{OL} = 2.0\text{ mA}$           | 0.4                 | V             |
| $V_{OH1}$      | Output High Voltage |                                                                                     | $I_{OH} = -1.0\text{ mA}$          | $V_{CC} - 0.8$      | V             |
| $V_{OL2}$      | Output Low Voltage  | $2.7\text{V} \leq V_{CC} \leq 5.5\text{V}$                                          | $I_{OL} = 0.15\text{ mA}$          | 0.2                 | V             |
| $V_{OH2}$      | Output High Voltage |                                                                                     | $I_{OH} = -100\text{ }\mu\text{A}$ | $V_{CC} - 0.2$      | V             |

Note: 1. This parameter is preliminary and Atmel may change the specifications upon further characterization.

2.  $V_{IL}$  min and  $V_{IH}$  max are reference only and are not tested.

## AC Characteristics

Applicable over recommended operating range from  $T_{AI} = -40^{\circ}\text{C}$  to  $+85^{\circ}\text{C}$ ,  $T_{AE} = -40^{\circ}\text{C}$  to  $+125^{\circ}\text{C}$ ,  $V_{CC} = \text{As Specified}$ ,  $CL = 1$  TTL Gate and 100 pF (unless otherwise noted).

| Symbol                   | Parameter                          | Voltage                | Min        | Max        | Units         |
|--------------------------|------------------------------------|------------------------|------------|------------|---------------|
| $f_{SCK}$                | SCK Clock Frequency                | 4.5 - 5.5<br>2.7 - 5.5 | 0<br>0     | 3.0<br>2.1 | MHz           |
| $t_{RI}$                 | Input Rise Time                    | 4.5 - 5.5<br>2.7 - 5.5 |            | 2<br>2     | $\mu\text{s}$ |
| $t_{FI}$                 | Input Fall Time                    | 4.5 - 5.5<br>2.7 - 5.5 |            | 2<br>2     | $\mu\text{s}$ |
| $t_{WH}$                 | SCK High Time                      | 4.5 - 5.5<br>2.7 - 5.5 | 133<br>200 |            | ns            |
| $t_{WL}$                 | SCK Low Time                       | 4.5 - 5.5<br>2.7 - 5.5 | 133<br>200 |            | ns            |
| $t_{CS}$                 | $\overline{CS}$ High Time          | 4.5 - 5.5<br>2.7 - 5.5 | 250<br>250 |            | ns            |
| $t_{CSS}$                | $\overline{CS}$ Setup Time         | 4.5 - 5.5<br>2.7 - 5.5 | 250<br>250 |            | ns            |
| $t_{CSH}$                | $\overline{CS}$ Hold Time          | 4.5 - 5.5<br>2.7 - 5.5 | 250<br>250 |            | ns            |
| $t_{SU}$                 | Data In Setup Time                 | 4.5 - 5.5<br>2.7 - 5.5 | 50<br>50   |            | ns            |
| $t_H$                    | Data In Hold Time                  | 4.5 - 5.5<br>2.7 - 5.5 | 50<br>100  |            | ns            |
| $t_{HD}$                 | $\overline{Hold}$ Setup Time       | 4.5 - 5.5<br>2.7 - 5.5 | 100<br>100 |            | ns            |
| $t_{CD}$                 | $\overline{Hold}$ Hold Time        | 4.5 - 5.5<br>2.7 - 5.5 | 200<br>200 |            | ns            |
| $t_V$                    | Output Valid                       | 4.5 - 5.5<br>2.7 - 5.5 | 0<br>0     | 133<br>200 | ns            |
| $t_{HO}$                 | Output Hold Time                   | 4.5 - 5.5<br>2.7 - 5.5 | 0<br>0     |            | ns            |
| $t_{LZ}$                 | $\overline{Hold}$ to Output Low Z  | 4.5 - 5.5<br>2.7 - 5.5 | 0<br>0     | 100<br>100 | ns            |
| $t_{HZ}$                 | $\overline{Hold}$ to Output High Z | 4.5 - 5.5<br>2.7 - 5.5 |            | 100<br>100 | ns            |
| $t_{DIS}$                | Output Disable Time                | 4.5 - 5.5<br>2.7 - 5.5 |            | 250<br>500 | ns            |
| $t_{WC}$                 | Write Cycle Time                   | 4.5 - 5.5<br>2.7 - 5.5 |            | 5<br>10    | ms            |
| Endurance <sup>(1)</sup> | 5.0V, 25°C, Page Mode              |                        | 1M         |            | Write Cycles  |

Note: 1. This parameter is characterized and is not 100% tested.

## Serial Interface Description

**MASTER:** The device that generates the serial clock.

**SLAVE:** Because the Serial Clock pin (SCK) is always an input, the AT25010/020/040 always operates as a slave.

**TRANSMITTER/RECEIVER:** The AT25010/020/040 has separate pins designated for data transmission (SO) and reception (SI).

**MSB:** The Most Significant Bit (MSB) is the first bit transmitted and received.

**SERIAL OP-CODE:** After the device is selected with  $\overline{CS}$  going low, the first byte will be received. This byte contains the op-code that defines the operations to be performed. The op-code also contains address bit A8 in both the READ and WRITE instructions.

**INVALID OP-CODE:** If an invalid op-code is received, no data will be shifted into the AT25010/020/040, and the serial output pin (SO) will remain in a high impedance state until the falling edge of  $\overline{CS}$  is detected again. This will reinitialize the serial communication.

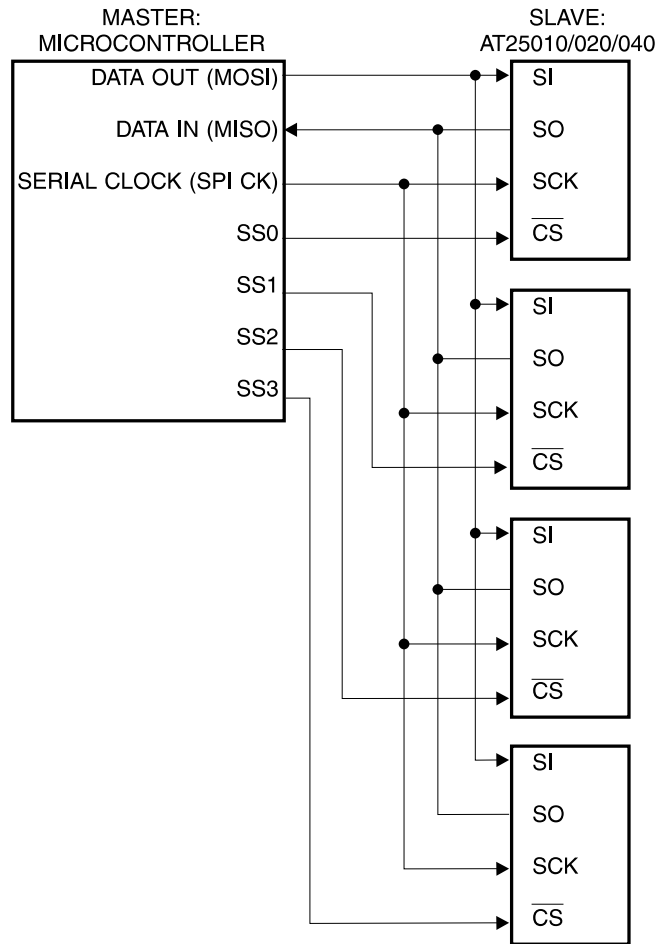
**CHIP SELECT:** The AT25010/020/040 is selected when the  $\overline{CS}$  pin is low. When the device is not selected, data will not be accepted via the SI pin, and the serial output pin (SO) will remain in a high impedance state.

**HOLD:** The  $\overline{HOLD}$  pin is used in conjunction with the  $\overline{CS}$  pin to select the AT25010/020/040. When the device is selected and a serial sequence is underway,  $\overline{HOLD}$  can be used to pause the serial communication with the master device without resetting the serial sequence. To pause, the  $\overline{HOLD}$  pin must be brought low while the SCK pin is low. To resume serial communication, the  $\overline{HOLD}$  pin is brought high while the SCK pin is low (SCK may still toggle during  $\overline{HOLD}$ ). Inputs to the SI pin will be ignored while the SO pin is in the high impedance state.

**WRITE PROTECT:** The write protect pin ( $\overline{WP}$ ) will allow normal read/write operations when held high. When the  $\overline{WP}$  pin is brought low, all write operations are inhibited.

$\overline{WP}$  going low while  $\overline{CS}$  is still low will interrupt a write to the AT25010/020/040. If the internal write cycle has already been initiated,  $\overline{WP}$  going low will have no effect on any write operation.

## SPI Serial Interface



## Functional Description

The AT25010/020/040 is designed to interface directly with the synchronous serial peripheral interface (SPI) of the 6805 and 68HC11 series of microcontrollers.

The AT25010/020/040 utilizes an 8-bit instruction register. The list of instructions and their operation codes are contained in Table 1. All instructions, addresses, and data are transferred with the MSB first and start with a high-to-low CS transition.

**Table 1.** Instruction Set for the AT25010/020/040

| Instruction Name | Instruction Format | Operation                   |
|------------------|--------------------|-----------------------------|
| WREN             | 0000 X110          | Set Write Enable Latch      |
| WRDI             | 0000 X100          | Reset Write Enable Latch    |
| RDSR             | 0000 X101          | Read Status Register        |
| WRSR             | 0000 X001          | Write Status Register       |
| READ             | 0000 A011          | Read Data from Memory Array |
| WRITE            | 0000 A010          | Write Data to Memory Array  |

Note: "A" represents MSB address bit A8.

**WRITE ENABLE (WREN):** The device will power up in the write disable state when  $V_{CC}$  is applied. All programming instructions must therefore be preceded by a Write Enable instruction. The  $\overline{WP}$  pin must be held high during a WREN instruction.

**WRITE DISABLE (WRDI):** To protect the device against inadvertent writes, the Write Disable instruction disables all programming modes. The WRDI instruction is independent of the status of the  $\overline{WP}$  pin.

**READ STATUS REGISTER (RDSR):** The Read Status Register instruction provides access to the status register. The READY/BUSY and Write Enable status of the device can be determined by the RDSR instruction. Similarly, the Block Write Protection bits indicate the extent of protection employed. These bits are set by using the WRSR instruction.

**Table 2.** Status Register Format

| Bit 7 | Bit 6 | Bit 5 | Bit 4 | Bit 3 | Bit 2 | Bit 1 | Bit 0            |
|-------|-------|-------|-------|-------|-------|-------|------------------|
| X     | X     | X     | X     | BP1   | BP0   | WEN   | $\overline{RDY}$ |

**Table 3.** Read Status Register Bit Definition

| Bit                                                            | Definition                                                                                                        |
|----------------------------------------------------------------|-------------------------------------------------------------------------------------------------------------------|
| Bit 0 ( $\overline{RDY}$ )                                     | Bit 0 = 0 ( $\overline{RDY}$ ) indicates the device is READY. Bit 0 = 1 indicates the write cycle is in progress. |
| Bit 1 (WEN)                                                    | Bit 1 = 0 indicates the device <i>is not</i> WRITE ENABLED. Bit 1 = 1 indicates the device is WRITE ENABLED.      |
| Bit 2 (BP0)                                                    | See Table 4.                                                                                                      |
| Bit 3 (BP1)                                                    | See Table 4.                                                                                                      |
| Bits 4-7 are 0s when device is not in an internal write cycle. |                                                                                                                   |
| Bits 0-7 are 1s during an internal write cycle.                |                                                                                                                   |

**WRITE STATUS REGISTER (WRSR):** The WRSR instruction allows the user to select one of four levels of protection. The AT25010/020/040 is divided into four array segments. Top quarter (1/4), Top half (1/2), or all of the memory segments can be protected. Any of the data within any selected segment will therefore be READ only. The block write protection levels and corresponding status register control bits are shown in Table 4.

The two bits, BP1 and BP0 are nonvolatile cells that have the same properties and functions as the regular memory cells (e.g. WREN,  $t_{WC}$ , RDSR).

**Table 4.** Block Write Protect Bits

| Level   | Status Register Bits |     | Array Addresses Protected |         |         |
|---------|----------------------|-----|---------------------------|---------|---------|
|         | BP1                  | BP0 | AT25010                   | AT25020 | AT25040 |
| 0       | 0                    | 0   | None                      | None    | None    |
| 1 (1/4) | 0                    | 1   | 60-7F                     | C0-FF   | 180-1FF |
| 2 (1/2) | 1                    | 0   | 40-7F                     | 80-FF   | 100-1FF |
| 3 (All) | 1                    | 1   | 00-7F                     | 00-FF   | 000-1FF |

**READ SEQUENCE (READ):** Reading the AT25010/020/040 via the SO (Serial Output) pin requires the following sequence. After the  $\overline{CS}$  line is pulled low to select a device, the READ op-code (including A8) is transmitted via the SI line followed by the byte address to be read (A7-A0). Upon completion, any data on the SI line will be ignored. The data (D7-D0) at the specified address is then shifted out onto the SO line. If only one byte is to be read, the  $\overline{CS}$  line should be driven high after the data comes out. The READ sequence can be continued since the byte address is automatically incremented and data will continue to be shifted out. When the highest address is reached, the address counter will roll over to the lowest address allowing the entire memory to be read in one continuous READ cycle.

**WRITE SEQUENCE (WRITE):** In order to program the AT25010/020/040, the Write Protect pin ( $\overline{WP}$ ) must be held high and two separate instructions must be executed. First, the device **must be write enabled** via the Write Enable (WREN) Instruction. Then a Write (WRITE) Instruction may be executed. Also, the address of the memory location(s) to be programmed must be outside the protected address field location selected by the Block Write Protection Level. During an internal write cycle, all commands will be ignored except the RDSR instruction.

A Write Instruction requires the following sequence. After the  $\overline{CS}$  line is pulled low to select the device, the WRITE op-code (including A8) is transmitted via the SI line followed by the byte address (A7-A0) and the data (D7-D0) to be programmed. Programming will start after the  $\overline{CS}$  pin is brought high. (The LOW to High transition of the  $\overline{CS}$  pin must occur during the SCK low time immediately after clocking in the D0 (LSB) data bit.

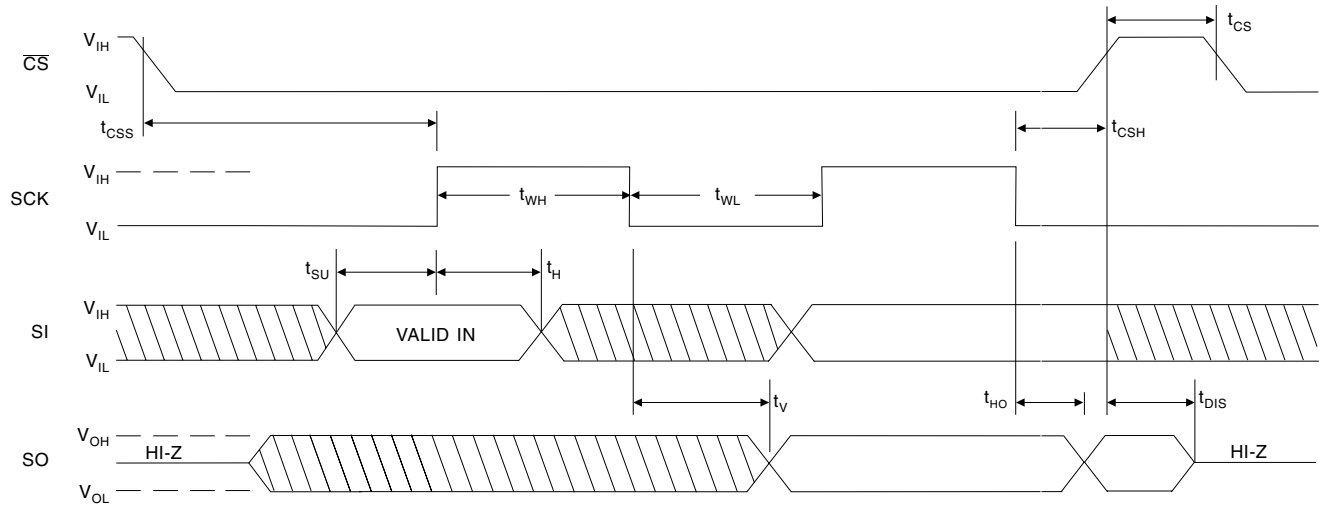
The READY/BUSY status of the device can be determined by initiating a READ STATUS REGISTER (RDSR) Instruction. If Bit 0 = 1, the WRITE cycle is still in progress. If Bit 0 = 0, the WRITE cycle has ended. Only the READ STATUS REGISTER instruction is enabled during the WRITE programming cycle.

The AT25010/020/040 is capable of an 8-byte PAGE WRITE operation. After each byte of data is received, the three low order address bits are internally incremented by one; the six high order bits of the address will remain constant. If more than 8 bytes of data are transmitted, the address counter will roll over and the previously written data will be overwritten. The AT25010/020/040 is automatically returned to the write disable state at the completion of a WRITE cycle.

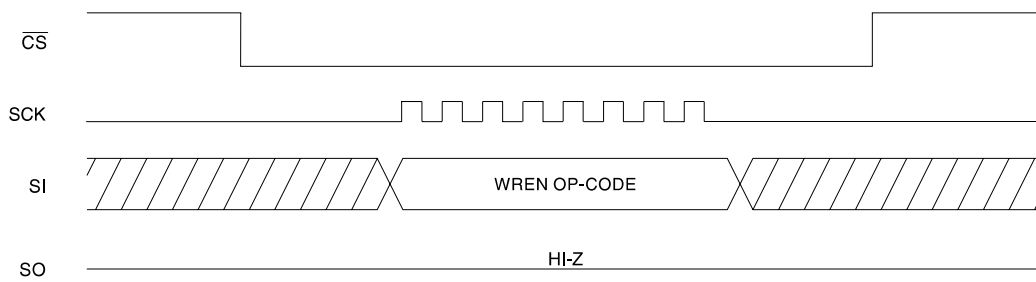
**NOTE:** If the  $\overline{WP}$  pin is brought low or if the device is not Write enabled (WREN), the device will ignore the Write instruction and will return to the standby state, when  $\overline{CS}$  is brought high. A new CS falling edge is required to re-initiate the serial communication.

## Timing Diagrams

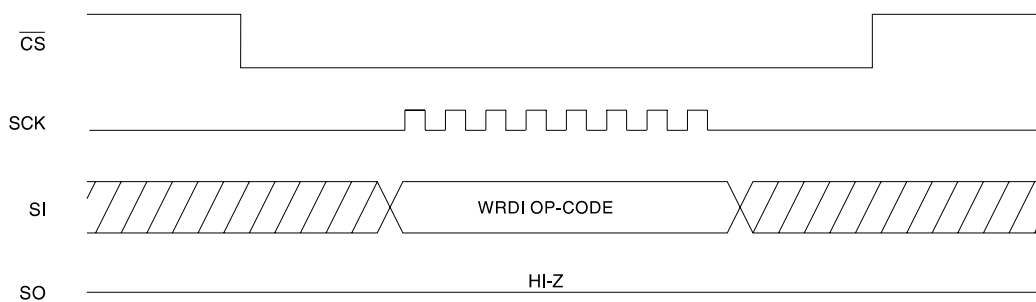
### Synchronous Data Timing (for mode 0)



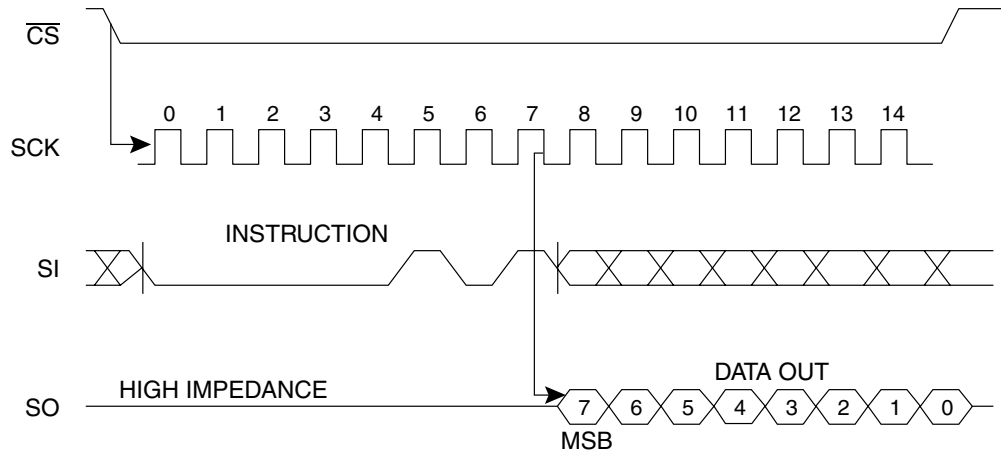
### WREN Timing



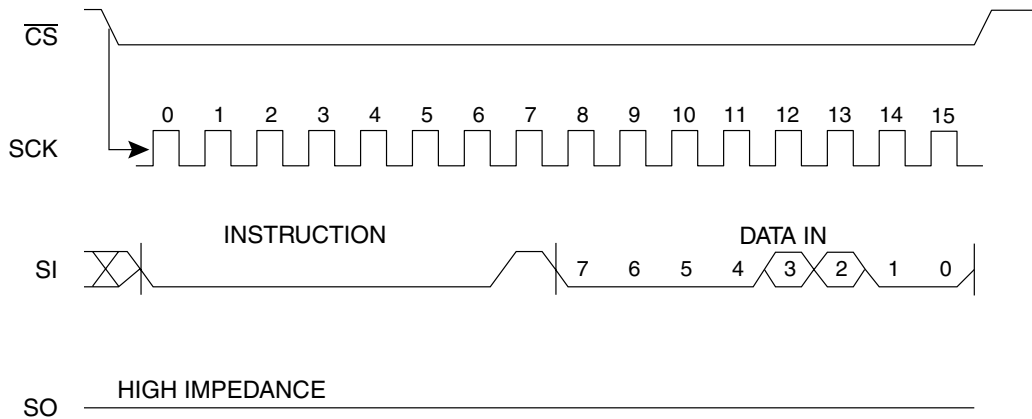
### WRDI Timing



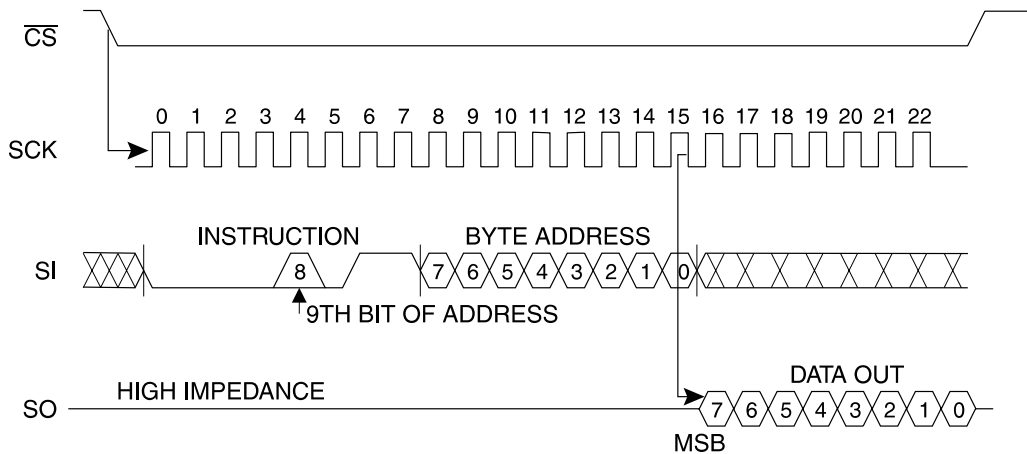
## RDSR Timing



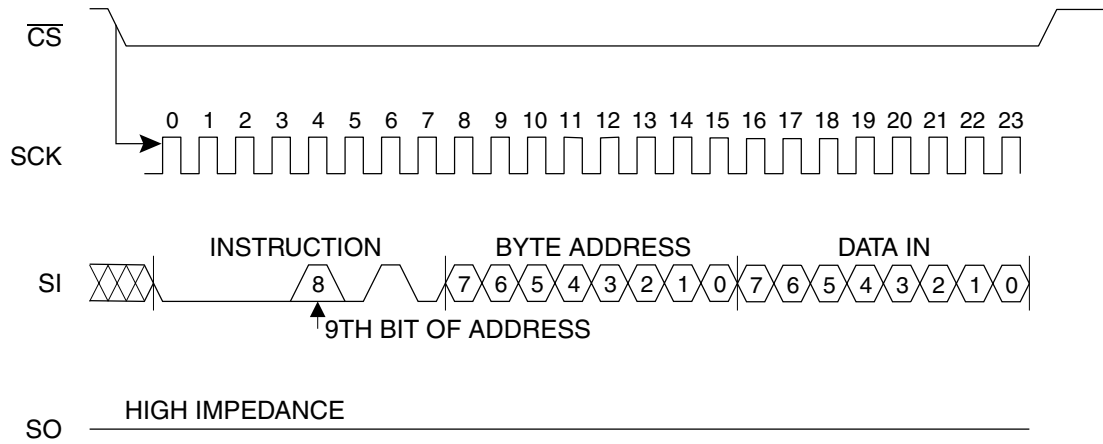
## WRSR Timing



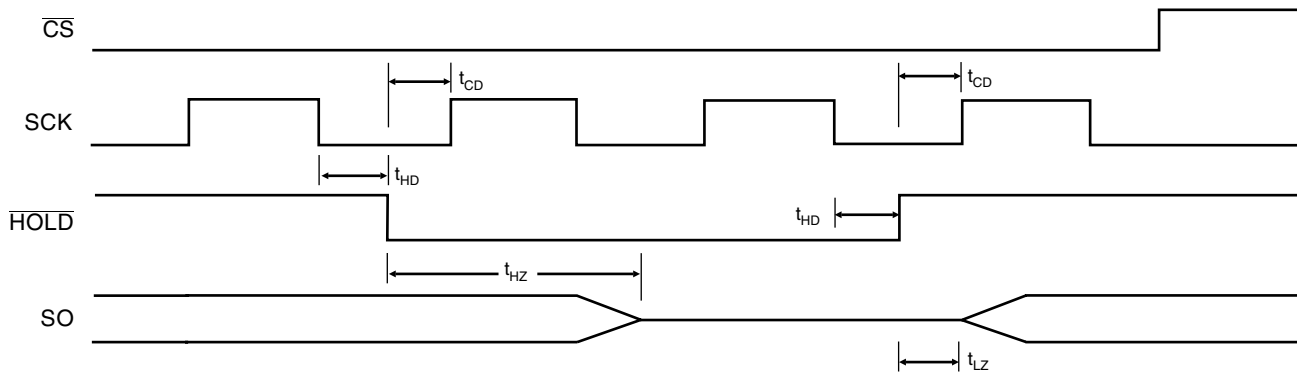
## READ Timing



## WRITE Timing



## HOLD Timing





## AT25010 Ordering Information

| Ordering Code                                                                     | Package                  | Operation Range                                     |
|-----------------------------------------------------------------------------------|--------------------------|-----------------------------------------------------|
| AT25010-10PI-2.7<br>AT25010N-10SI-2.7<br>AT25010Y1-10YI-2.7<br>AT25010Y2-10YI-2.7 | 8P3<br>8S1<br>8Y1<br>8Y2 | Industrial<br>(-40°C to 85°C)                       |
| AT25010N-10SJ-2.7                                                                 | 8S1                      | Lead-Free/Industrial Temperature<br>(-40°C to 85°C) |
| AT25010N-10SE-2.7                                                                 | 8S1                      | High Grade/Extended Temperature<br>(-40°C to 125°C) |

Note: For 2.7V devices used in the 4.5V to 5.5V range, please refer to performance values in the AC and DC Characteristics tables.

| Package Type |                                                                                        |
|--------------|----------------------------------------------------------------------------------------|
| <b>8P3</b>   | 8-lead, 0.300" Wide, Plastic Dual Inline Package (PDIP)                                |
| <b>8S1</b>   | 8-lead, 0.150" Wide, Plastic Gull Wing Small Outline Package (JEDEC SOIC)              |
| <b>8Y1</b>   | 8-lead, 4.90 x 3.00 mm Body, Dual Footprint, Non-leaded, Miniature Array Package (MAP) |
| <b>8Y2</b>   | 8-lead, 6.40 x 3.00 mm Body, Dual Footprint, Non-leaded, Thin Array Package (TAP)      |
| Options      |                                                                                        |
| <b>-2.7</b>  | Low Voltage (2.7V to 5.5V)                                                             |

## AT25020 Ordering Information

| Ordering Code                                                                     | Package                  | Operation Range                                     |
|-----------------------------------------------------------------------------------|--------------------------|-----------------------------------------------------|
| AT25020-10PI-2.7<br>AT25020N-10SI-2.7<br>AT25020Y1-10YI-2.7<br>AT25020Y2-10YI-2.7 | 8P3<br>8S1<br>8Y1<br>8Y2 | Industrial<br>(-40°C to 85°C)                       |
| AT25020N-10SJ-2.7                                                                 | 8S1                      | Lead-Free/Industrial Temperature<br>(-40°C to 85°C) |
| AT25020N-10SE-2.7                                                                 | 8S1                      | High Grade/Extended Temperature<br>(-40°C to 125°C) |

Note: For 2.7V devices used in the 4.5V to 5.5V range, please refer to performance values in the AC and DC Characteristics tables.

| Package Type |                                                                                        |
|--------------|----------------------------------------------------------------------------------------|
| <b>8P3</b>   | 8-lead, 0.300" Wide, Plastic Dual Inline Package (PDIP)                                |
| <b>8S1</b>   | 8-lead, 0.150" Wide, Plastic Gull Wing Small Outline Package (JEDEC SOIC)              |
| <b>8Y1</b>   | 8-lead, 4.90 x 3.00 mm Body, Dual Footprint, Non-leaded, Miniature Array Package (MAP) |
| <b>8Y2</b>   | 8-lead, 6.40 x 3.00 mm Body, Dual Footprint, Non-leaded, Thin Array Package (TAP)      |
| Options      |                                                                                        |
| <b>-2.7</b>  | Low Voltage (2.7V to 5.5V)                                                             |

## AT25040 Ordering Information

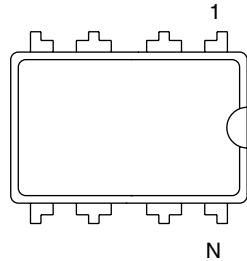
| Ordering Code                                                                     | Package                  | Operation Range                                     |
|-----------------------------------------------------------------------------------|--------------------------|-----------------------------------------------------|
| AT25040-10PI-2.7<br>AT25040N-10SI-2.7<br>AT25040Y1-10YI-2.7<br>AT25040Y2-10YI-2.7 | 8P3<br>8S1<br>8Y1<br>8Y2 | Industrial<br>(-40°C to 85°C)                       |
| AT25040N-10SJ-2.7                                                                 | 8S1                      | Lead-Free/Industrial Temperature<br>(-40°C to 85°C) |
| AT25040N-10SE-2.7                                                                 | 8S1                      | High Grade/Extended Temperature<br>(-40°C to 125°C) |

Note: For 2.7V devices used in the 4.5V to 5.5V range, please refer to performance values in the AC and DC Characteristics tables.

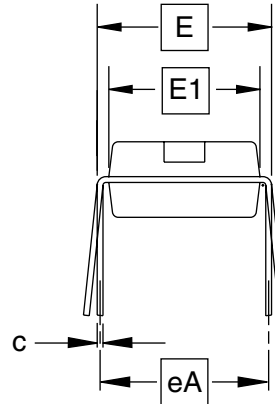
| Package Type |                                                                                        |
|--------------|----------------------------------------------------------------------------------------|
| <b>8P3</b>   | 8-lead, 0.300" Wide, Plastic Dual Inline Package (PDIP)                                |
| <b>8S1</b>   | 8-lead, 0.150" Wide, Plastic Gull Wing Small Outline Package (JEDEC SOIC)              |
| <b>8Y1</b>   | 8-lead, 4.90 x 3.00 mm Body, Dual Footprint, Non-leaded, Miniature Array Package (MAP) |
| <b>8Y2</b>   | 8-lead, 6.40 x 3.00 mm Body, Dual Footprint, Non-leaded, Thin Array Package (TAP)      |
| Options      |                                                                                        |
| <b>-2.7</b>  | Low Voltage (2.7V to 5.5V)                                                             |

## Packaging Information

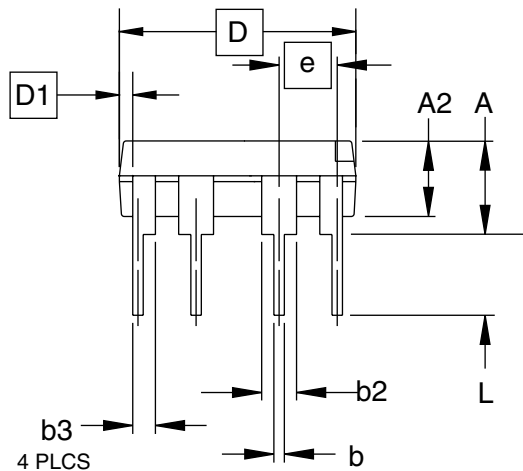
### 8P3 – PDIP



Top View



End View



Side View

**COMMON DIMENSIONS**  
(Unit of Measure = inches)

| SYMBOL | MIN       | NOM   | MAX   | NOTE |
|--------|-----------|-------|-------|------|
| A      |           |       | 0.210 | 2    |
| A2     | 0.115     | 0.130 | 0.195 |      |
| b      | 0.014     | 0.018 | 0.022 | 5    |
| b2     | 0.045     | 0.060 | 0.070 | 6    |
| b3     | 0.030     | 0.039 | 0.045 | 6    |
| c      | 0.008     | 0.010 | 0.014 |      |
| D      | 0.355     | 0.365 | 0.400 | 3    |
| D1     | 0.005     |       |       | 3    |
| E      | 0.300     | 0.310 | 0.325 | 4    |
| E1     | 0.240     | 0.250 | 0.280 | 3    |
| e      | 0.100 BSC |       |       |      |
| eA     | 0.300 BSC |       |       | 4    |
| L      | 0.115     | 0.130 | 0.150 | 2    |

- Notes:
1. This drawing is for general information only; refer to JEDEC Drawing MS-001, Variation BA for additional information.
  2. Dimensions A and L are measured with the package seated in JEDEC seating plane Gauge GS-3.
  3. D, D1 and E1 dimensions do not include mold Flash or protrusions. Mold Flash or protrusions shall not exceed 0.010 inch.
  4. E and eA measured with the leads constrained to be perpendicular to datum.
  5. Pointed or rounded lead tips are preferred to ease insertion.
  6. b2 and b3 maximum dimensions do not include Dambar protrusions. Dambar protrusions shall not exceed 0.010 (0.25 mm).

01/09/02



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**TITLE**

**8P3**, 8-lead, 0.300" Wide Body, Plastic Dual  
In-line Package (PDIP)

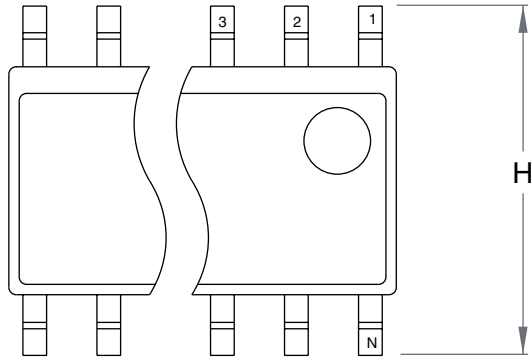
**DRAWING NO.**

8P3

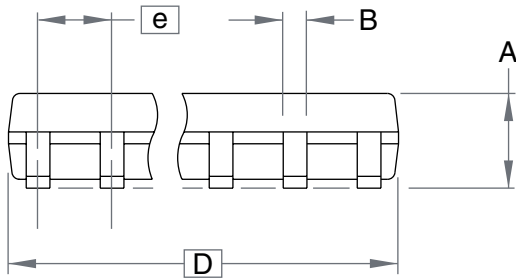
**REV.**

B

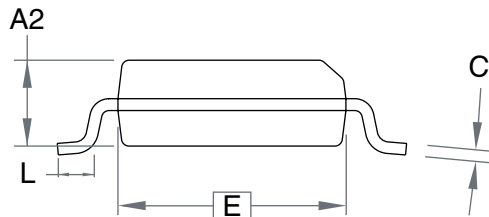
## 8S1 – JEDEC SOIC



Top View



Side View



End View

**COMMON DIMENSIONS**  
(Unit of Measure = mm)

| SYMBOL | MIN      | NOM | MAX  | NOTE |
|--------|----------|-----|------|------|
| A      | –        | –   | 1.75 |      |
| B      | –        | –   | 0.51 |      |
| C      | –        | –   | 0.25 |      |
| D      | –        | –   | 5.00 |      |
| E      | –        | –   | 4.00 |      |
| e      | 1.27 BSC |     |      |      |
| H      | –        | –   | 6.20 |      |
| L      | –        | –   | 1.27 |      |

Note: This drawing is for general information only. Refer to JEDEC Drawing MS-012 for proper dimensions, tolerances, datums, etc.

10/10/01



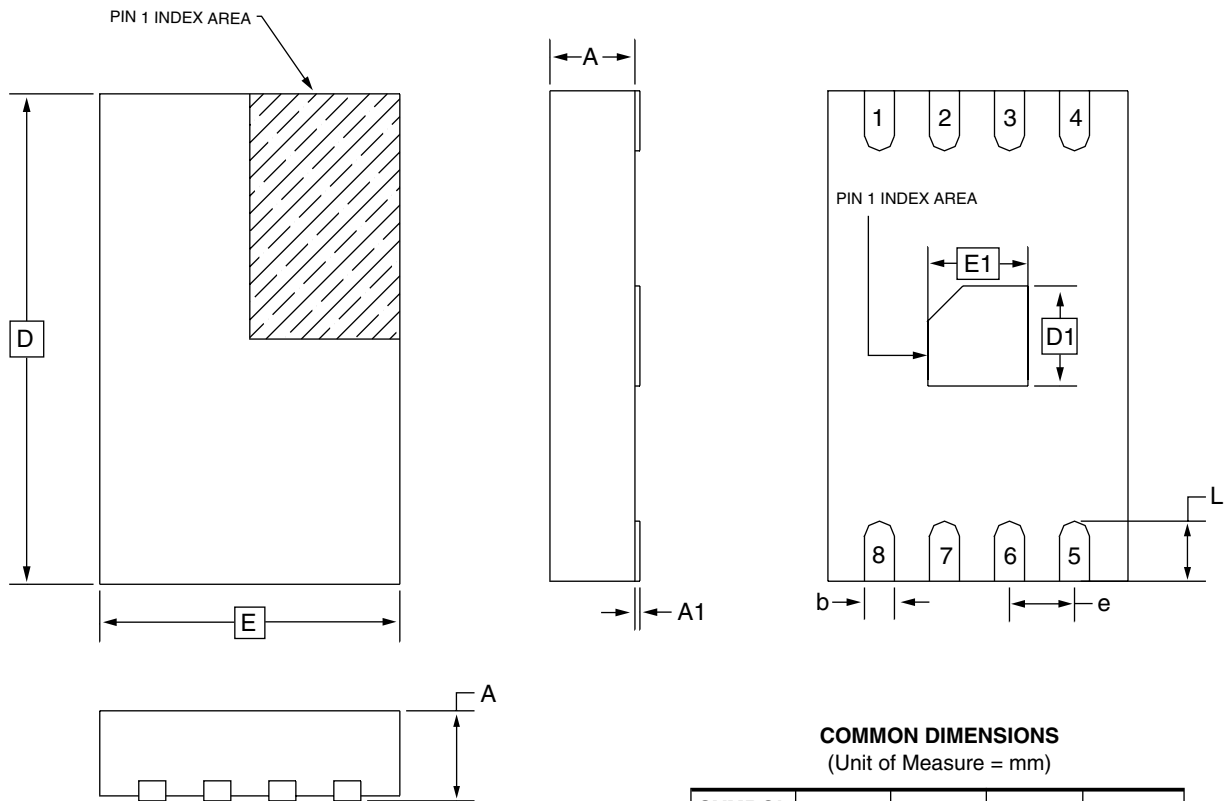
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San Jose, CA 95131

**TITLE**  
**8S1**, 8-lead (0.150" Wide Body), Plastic Gull Wing  
Small Outline (JEDEC SOIC)

**DRAWING NO.**  
8S1

**REV.**  
A

## 8Y1 – MAP



**COMMON DIMENSIONS**  
(Unit of Measure = mm)

| SYMBOL | MIN      | NOM  | MAX  | NOTE |
|--------|----------|------|------|------|
| A      | –        | –    | 0.90 |      |
| A1     | 0.00     | –    | 0.05 |      |
| D      | 4.70     | 4.90 | 5.10 |      |
| E      | 2.80     | 3.00 | 3.20 |      |
| D1     | 0.85     | 1.00 | 1.15 |      |
| E1     | 0.85     | 1.00 | 1.15 |      |
| b      | 0.25     | 0.30 | 0.35 |      |
| e      | 0.65 TYP |      |      |      |
| L      | 0.50     | 0.60 | 0.70 |      |

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**TITLE**

**8Y1**, 8-lead (4.90 x 3.00 mm Body) MSOP Array Package  
(MAP) Y1

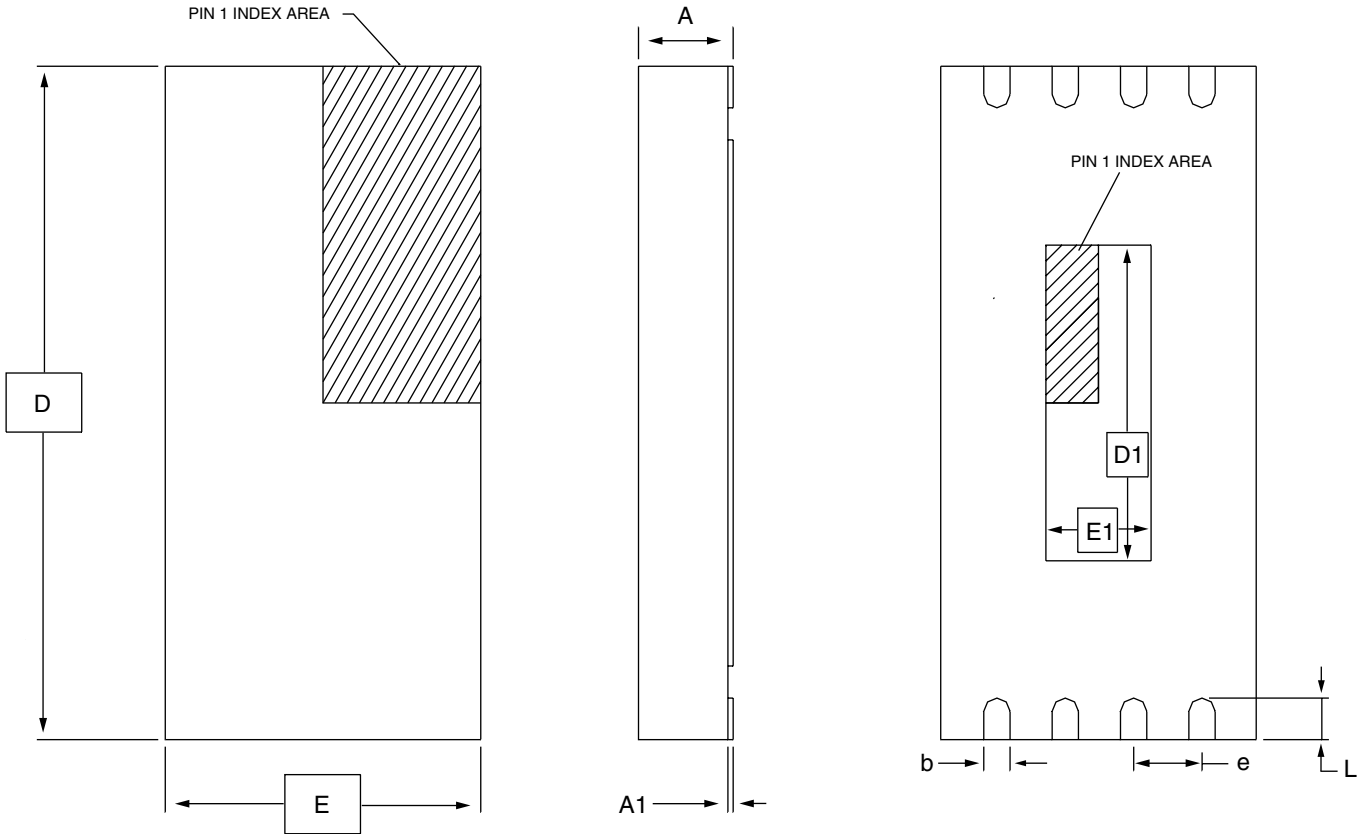
**DRAWING NO.**

8Y1

**REV.**

B

## 8Y2 – TAP



**COMMON DIMENSIONS**  
(Unit of Measure = mm)

| SYMBOL | MIN      | NOM  | MAX  | NOTE |
|--------|----------|------|------|------|
| A      | –        | –    | 0.90 |      |
| A1     | 0.00     | –    | 0.05 |      |
| D      | 6.20     | 6.40 | 6.60 |      |
| E      | 2.80     | 3.00 | 3.20 |      |
| D1     | 2.85     | 3.00 | 3.15 |      |
| E1     | 0.85     | 1.00 | 1.15 |      |
| b      | 0.20     | 0.25 | 0.30 |      |
| e      | 0.65 TYP |      |      |      |
| L      | 0.30     | 0.40 | 0.50 |      |

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### TITLE

**8Y2**, 8-lead (6.40 x 3.00 mm Body) TSSOP Array Package  
(TAP) Y2

### DRAWING NO.

8Y2

### REV.

A



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